

@aniit

Series grouping of resistances

Equivalent resistance, $R_e = R_1 + R_2 + ... + R_n$ In this case same current flows through each resistance but potential difference distributes in the ratio of resistance

Parallel grouping of resistances Equivalent resistance.

 $\frac{1}{R_p} = \frac{1}{R_1} + \frac{1}{R_2} + \dots + \frac{1}{R_p}$

In this case same potential acorss each resistance but current distributes in the reverse ratio of their resistances

area of cross-section decreases

 $\frac{1}{n^2}$ times so the resistance

becomes n^4 times i.e., $R_2 = n^4 R_1$. After stretching, if length of a conductor increases by x%, then resistance will increase by 2x%(valid only if x < 10%).

On length (ℓ) and area Grouping of resistances

Resistance, $R \propto \frac{\ell^2}{}$

 $\left.\begin{array}{c}
R \propto l \\
\propto \frac{1}{A}
\end{array}\right\} R = \rho \frac{l}{A}$

of cross-section (A)

 ρ = resistivity Resistivity depends on the material of the conductor only.

On temperature

 $R_t = R_0(t + \alpha t)$

 $\alpha = \text{temperature}$

coefficient of

resistance

 ℓ = length and m = mass ofconducting wire Dependence of

Current density (J) Current per unit cross sectional area

resistance

Electric Current (I) The time rate of flow of charge (O) through any cross-section

$$I = \frac{Q}{t}$$
; $I = \lim_{\Delta t \to 0} \frac{\Delta Q}{\Delta t} = \frac{dQ}{dt}$

Drift velocity (V_d)

Average uniform velocity acquired by free

electrons
$$V_d = \frac{i}{\text{neA}} = \frac{J}{ne} = \frac{V}{\rho \ell ne}$$

$$V_d = \frac{E}{fne}$$

Direction of drift velocity for electrons in a metal is opposite to that of applied electric

Mobitity (µ)

Drift velocity per unit electric field $\mu = \frac{V_d}{E}$

Resistance (R) Obstruction offered to flow of electrons

Ohm's law If the physical conditions remain same. current $I \propto V \Rightarrow V = IR$ R-electric resistance Substances which obey obm's law called ohmic and that do not obey called non-ohmic substances.

Conductivity (σ)

Reciprocal of resistivity $\sigma = \frac{1}{2}$ Conductance, C = -

resistance

After stretching, if length increases by n times then resistance will increase by n^2 times i.e., $R_2 = n^2 R_1$. Similarly if

radius be reduced to $\frac{1}{n}$ times then

Colour coding of Resistance

 $R = AB \times C \pm D\% A.B -$ First two significant figures of resistance C-multiplier D-tolerance to remembers the sequence of colour code B B Roy Great Britain Very Good Wife

CURRENT ELECTRICTY

• Using n coductors of equal resistance, the number of possible combinations is 2ⁿ⁻¹.

- If the resistances of n conductors are totally different, then the number of possible combinations will be 2ⁿ.
- If n identical resistances are first connected in series and then in parallel, the ratio of the equivalent resistance is given by
- If a wire of resistance R is cut in n equal parts and then these parts are collected to form a bundle, then equivalent resistance of combination will be $\frac{R}{R}$
- If equivalent resistance of R_1 and R_2 in series and parallel be R_s and R_p respectively, then $R_1 = \frac{1}{2} \left[R_s + \sqrt{R_s^2 - 4R_s R_p} \right]$ and $R_2 = \frac{1}{2} \left[R_s - \sqrt{R_s^2 - 4R_s R_p} \right]$

Electric cell Source of energy that maintains continuous flow of charge in a circuit

Electrical energy

Jule's heating law H = I2Rt; Electrical

In series combination, power

In parallel combination $P_{total} = nP$

Kirchhoff's laws

2nd law/Loop

rule Algebraic

sum of changes in

any closed loop is

potential around

zero. $\Sigma^{E} = \Sigma^{IR}$

consumed $P_{\text{total}} = \frac{P}{n}$ Brightness \propto power \propto V \propto

Brightness ∞ power ∞ I ∞

1st law/Junction

current meeting at

a junction is zero

Potential gradient (x)

of potentiometer wire.

potentiometer wire (i)

of potentiometer

primary circuit

(i.e., Area of cross-section)

(d) The current flowing through

Potential difference per unit

length of wire $x = \frac{V}{L} = \frac{\text{volt}}{m}$ where $V = iR = \left(\frac{e}{R + R_h + r}\right)R$ So,

(i) Potential gradient directly depends upon

(a) The resistance pre unit length (R/L)

(c) The specific resistance of the material

(ii) potential gradient indirectly depends upon

(b) The radius of potentiometer wire

law Algebraic

sum of all the

i.e $\Sigma I = 0$

 $\propto R$ $\propto t$ Power = P = $\frac{V^2}{R}$

Cells in series Current

in the circuit, $I = \frac{n\epsilon}{R + nr}$

Cells in parallel

Current in the circuit current $I = \frac{\varepsilon}{}$

Groupings of cells

Cells in series and parallel i.e. mixed Current in the circuit, $I = \frac{n\varepsilon}{n}$

m

Meter bridge Based on Wheatstone bridge

 $\frac{P}{Q} = \frac{R}{S} \Rightarrow \frac{l}{100 - l} = \frac{R}{S}$

Balanced condition of wheatstone bridge P R

 $\frac{1}{Q} = \frac{R}{S}$

Potentiometer used to (i) Compare emfs

(ii) Find internal resistance of cell $r = \left(\frac{E}{V} - 1\right)S$

Sensitivity of potentio-

meter

A potentiometer is more sensitive, if it measures a small potential difference more accurately.

- (i) The sensitivity of potentiometer is assessed by its potential gradient. The sensitivity is inversely proportional to the ptential gradient.
- (ii) In order to increase the sensitivity of potentiometer.
- (a) The resistance in primary circuit will have to be decreased.
- (b) The length of (a) The emf of battery in the primary circuit (b) The resistance of rheostat in the potentiometer wire will have to be increased

· When cell is discharging: When cell is discharging current inside the cell is from cathode to anode. Current

or
$$E = IR + Ir = V + Ir$$
 or $V = E - Ir$

When current is drawn from the cell potential difference is less than emf of cell Greater is the current drawn from the cell smaller is the terminal voltage. When a large current is drawn from a cell its terminal voltage is reduced.

• When cell is charging: When cell is charging current inside the cell is from anode to cathode. Current $I = \frac{V - E}{r}$ or V = E + Ir

During charging terminal potential difference is greater than emf of cell.

When cell is in open circuit: In open circuit

$$R = \infty$$
 $\therefore I = \frac{E}{R+1} = 0$ So $V = E$

In open circuit terminal potential difference is equal to emf and is the maximum potential difference which a cell can provide.

· When cell is short circuited: In short circuit

O So
$$I = \frac{-E}{(R+r)}$$
 and $V = IR = 0$

In short circuit current from cell is maximum and terminal potential difference is zero.

Power transferred to load by cell:

$$P = I^2 R = \frac{E^2 R}{(r+R)^2}$$
 so, $P = P_{max}$

if $\frac{dP}{dR}$ and $P = P_{max}$ if r = R

Power transferred by cell to load is maximum

when r = R and $P_{\text{max}} = \frac{E^2}{4r} = \frac{E^2}{4R}$